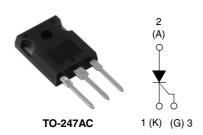


Vishay High Power Products

Phase Control SCR, 35 A



PRODUCT SUMMARY					
V _T at 40 A	< 1.45 V				
I _{TSM}	500 A				
V _{RRM}	800/1200 V				

DESCRIPTION/FEATURES

The 40TPS...A High Voltage Series of silicon controlled rectifiers are specifically designed for medium power switching and phase control applications. The glass passivation technology used has reliable operation up to 125 °C junction temperature. Low Igt parts available.

Typical applications are in input rectification (soft start) and these products are designed to be used with Vishay HPP input diodes, switches and output rectifiers which are available in identical package outlines.

This product has been designed and qualified for industrial level.

MAJOR RATINGS AND CHARACTERISTICS							
PARAMETER	TEST CONDITIONS	VALUES	UNITS				
I _{T(AV)}	Sinusoidal waveform	35	Α				
I _{RMS}	1	55	A				
V _{RRM} /V _{DRM}		800/1200	V				
I _{TSM}		500	Α				
V _T	40 A, T _J = 25 °C	1.45	V				
dV/dt		1000	V/μs				
dl/dt		100	A/μs				
T _J		- 40 to 125	°C				

VOLTAGE RATINGS								
PART NUMBER	V _{RRM} /V _{DRM} , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} /I _{DRM} AT 125 °C mA					
40TPS08A	800	900						
40TPS12A	1200	1300	10					
40TPS08	800	900	10					
40TPS12	1200	1300						

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PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average on-state current	I _{T(AV)}	T _C = 79 °C, 180° conduction half sine wave		35	
Maximum continuous RMS on-state current as AC switch	I _{T(RMS)}			55	Α
Maximum peak, one-cycle	1	10 ms sine pulse, rated V _{RRM} applied		500	
non-repetitive surge current	I _{TSM}	10 ms sine pulse, no voltage reapplied		600	
Maximum 12t for frains	l ² t	10 ms sine pulse, rated V _{RRM} applied	Initial $T_J = T_{J}$ maximum	1250	A ² s
Maximum I ² t for fusing	1-1	10 ms sine pulse, no voltage reapplied	TJITIAXIITIAITI	1760	
Maximum I ² √t for fusing	I ² √t	t = 0.1 to 10 ms, no voltage reapplied		12 500	A²√s
Low level value of threshold voltage	V _{T(TO)1}	·		1.02	٧
High level value of threshold voltage	V _{T(TO)2}	T _J = 125 °C		1.23	V
Low level value of on-state slope resistance	r _{t1}			9.74	
High level value of on-state slope resistance	r _{t2}	2_		7.50	mΩ
Maximum peak on-state voltage	V_{TM}	110 A, T _J = 25 °C		1.85	٧
Maximum rate of rise of turned-on current	dl/dt	T _J = 25 °C		100	A/μs
Maximum holding current	I _H	20 3		150	
Maximum latching current	ΙL	132		300	
Maximum reverse and direct leakage current		T _J = 25 °C	,	0.5	mA
	I _{RRM} I _{DRM}	T _J = 125 °C V _R = Rated V _{RRM} /V	DRM	10	
Maximum rate of rise of off-state voltage 40TPS08				500	V/µs
Maximum rate of rise of off-state voltage 40TPS12 dV/dt $T_J = T_J$ maximum, linear to 80 % V_{DRM} , R_g -k = Open		1000	V/µs		

TRIGGERING					
PARAMETER	SYMBOL		TEST CONDITIONS	VALUES	UNITS
Maximum peak gate power	P _{GM}			10	w
Maximum average gate power	P _{G(AV)}			2.5	VV
Maximum peak gate current	I _{GM}			2.5	Α
Maximum peak negative gate voltage	- V _{GM}			10	٧
		T _J = - 40 °C		4.0	
Maximum required DC gate voltage to trigger	V _{GT}	T _J = 25 °C	Anode supply = 6 V resistive load	2.5	٧
vollage to ingger		T _J = 125 °C		1.7	
		T _J = - 40 °C		270	
Maximum required DC gate current to trigger	1	T _J = 25 °C		150	mA
Maximum required DC gate current to trigger	I _{GT}	T _J = 125 °C		80	IIIA
		T_J = 25 °C, for 40TPS08A and 40TPS12A		40	
Maximum DC gate voltage not to trigger	V_{GD}	$T_J = 125$ °C, $V_{DRM} = Rated value$ 0.		0.25	٧
Maximum DC gate current not to trigger	I _{GD}			6	mA

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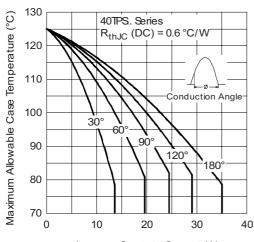
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PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage temperature range		T _J , T _{Stg}		- 40 to 125	°C	
Maximum thermal resistance, junction to case		R _{thJC} DC operation		0.6		
Maximum thermal resistance junction to ambient	e,	R _{thJA}	- DO operation	40	°C/W	
Maximum thermal resistance, case to heatsink		R_{thCS}	Mounting surface, smooth and greased	0.2		
Approximate weight				6	g	
				0.21	oz.	
Mounting torque -	minimum			6 (5)	kgf · cm	
Woulding torque	maximum			12 (10)	(lbf · in)	
				40TP	S08A	
Mandana da da a		Case style TO-247AC		40TPS12A		
Marking device				40TPS08		
				40TPS12		
			i.co.			

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Average On-state Current (A)
Fig. 1 - Current Rating Characteristics

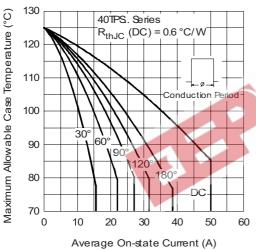


Fig. 2 - Current Rating Characteristics

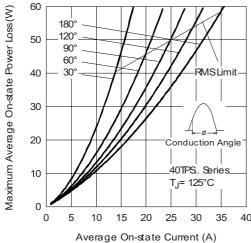


Fig. 3 - On-State Power Loss Characteristics

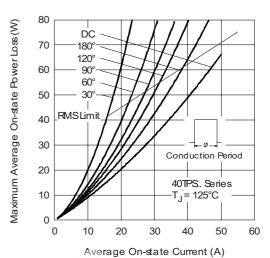
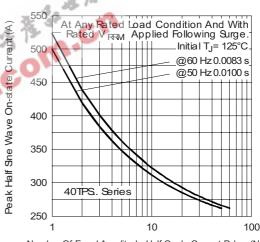


Fig. 4 - On-State Power Loss Characteristics



Number Of Equal Amplitude Half Cycle Current Pulæs (N)

Fig. 5 - Maximum Non-Repetitive Surge Current

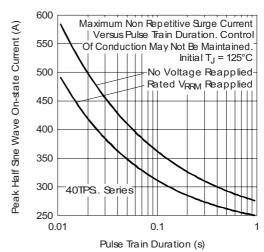


Fig. 6 - Maximum Non-Repetitive Surge Current

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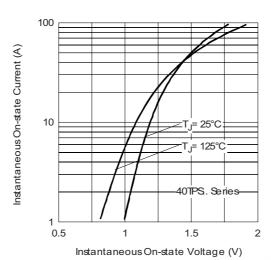
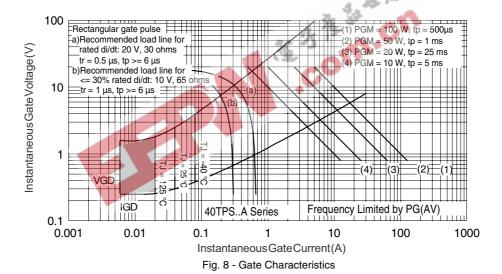


Fig. 7 - On-State Voltage Drop Characteristics



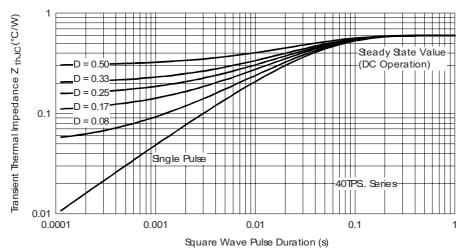


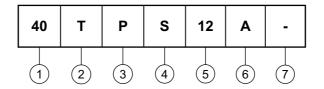
Fig. 9 - Thermal Impedance Z_{thJC} Characteristics

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ORDERING INFORMATION TABLE

Device code



- 1 Current rating (40 = 40 A)
- 2 Circuit configuration:

T = Thyristor

3 - Package:

P = TO-247

4 - Type of silicon:

S = Standard recovery rectifier

08 = 800 V 12 = 1200 V

- 5 Voltage ratings
 - • A = Low Igt selection 40 mA maximum
 - None = Standard Igt selection
- 7 None = Standard production
 - PbF = Lead (Pb)-free

LINKS TO RELATED DOCUMENTS					
Dimensions				http://www.vishay.com/doc?95223	
Part marking information				http://www.vishay.com/doc?95226	





Vishay

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